


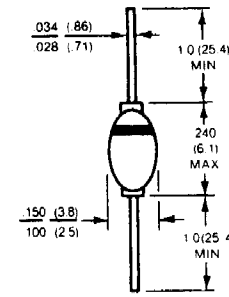
New Jersey Semi-Conductor Products, Inc.

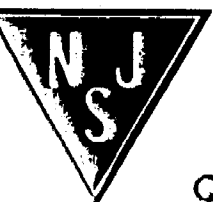
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RG1 SERIES

MINIATURE GLASS PASSIVATED JUNCTION FAST SWITCHING RECTIFIER

	VOLTAGE RANGE 50 to 1000 Volts CURRENT 1.0 Ampere																																																																																																												
FEATURES <ul style="list-style-type: none"> • High temperature metallurgically bonded — no compression contacts as found in diode-constructed rectifiers • Glass passivated junction in a DO-204AP package • 1 ampere operation at $T_A = 55^\circ\text{C}$ with no thermal runaway • Typical I_R less than $1\ \mu\text{A}$ • Fast switching for high efficiency. • Exceeds environmental standards of MIL-STD-19500 • High temperature soldering guaranteed $350^\circ\text{C}/10$ seconds/.375" (9.5mm) lead length/5 lbs., (2.3) tension 	DO-204AP  <p>Dimensions in inches and (millimeters)</p>																																																																																																												
MECHANICAL DATA Case: One piece glass, hermetically sealed Terminals: Axial leads, solderable per MIL-STD-202, Method 208 Polarity: Color band denotes cathode Mounting Position: Any Weight: .02 ounce, .56 gram																																																																																																													
MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS <small>Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.</small>																																																																																																													
	<table border="1"> <thead> <tr> <th></th> <th>RG1A</th> <th>RG1B</th> <th>RG1D</th> <th>RG1G</th> <th>RG1J</th> <th>RG1K</th> <th>RG1M</th> <th>UNITS</th> </tr> </thead> <tbody> <tr> <td>Maximum Recurrent Peak Reverse Voltage</td> <td>50</td> <td>100</td> <td>200</td> <td>400</td> <td>600</td> <td>800</td> <td>1000</td> <td>V</td> </tr> <tr> <td>Maximum RMS Voltage</td> <td>35</td> <td>70</td> <td>140</td> <td>280</td> <td>420</td> <td>560</td> <td>700</td> <td>V</td> </tr> <tr> <td>Maximum DC Blocking Voltage</td> <td>50</td> <td>70</td> <td>200</td> <td>400</td> <td>600</td> <td>800</td> <td>1000</td> <td>V</td> </tr> <tr> <td>Maximum Average Forward Rectified Current, .375" (9.5mm) Lead Length at $T_A = 55^\circ\text{C}$</td> <td colspan="7" style="text-align: center;">1.0</td> <td>A</td> </tr> <tr> <td>Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)</td> <td colspan="7" style="text-align: center;">30</td> <td>A</td> </tr> <tr> <td>Maximum Instantaneous Forward Voltage at 1.0A</td> <td colspan="7" style="text-align: center;">1.3</td> <td>V</td> </tr> <tr> <td>Maximum Full Load Reverse Current, Full Cycle Average, .375", (9.5mm) Lead Length at $T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$</td> <td colspan="7" style="text-align: center;">1.0 100</td> <td>μA μA</td> </tr> <tr> <td>Maximum DC Reverse Current, at Rated DC Blocking Voltage</td> <td colspan="7" style="text-align: center;">2.0</td> <td>μA</td> </tr> <tr> <td>Maximum Reverse Recovery Time (Note 1)</td> <td>150</td> <td>150</td> <td>150</td> <td>150</td> <td>200</td> <td>250</td> <td>500</td> <td>ns</td> </tr> <tr> <td>Typical Junction Capacitance (Note 2)</td> <td colspan="7" style="text-align: center;">10</td> <td>pF</td> </tr> <tr> <td>Operating and Storage Temperature Range, T_J, T_{STG}</td> <td colspan="7" style="text-align: center;">-65 to +175</td> <td>$^\circ\text{C}$</td> </tr> </tbody> </table>		RG1A	RG1B	RG1D	RG1G	RG1J	RG1K	RG1M	UNITS	Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V	Maximum RMS Voltage	35	70	140	280	420	560	700	V	Maximum DC Blocking Voltage	50	70	200	400	600	800	1000	V	Maximum Average Forward Rectified Current, .375" (9.5mm) Lead Length at $T_A = 55^\circ\text{C}$	1.0							A	Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	30							A	Maximum Instantaneous Forward Voltage at 1.0A	1.3							V	Maximum Full Load Reverse Current, Full Cycle Average, .375", (9.5mm) Lead Length at $T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	1.0 100							μA μA	Maximum DC Reverse Current, at Rated DC Blocking Voltage	2.0							μA	Maximum Reverse Recovery Time (Note 1)	150	150	150	150	200	250	500	ns	Typical Junction Capacitance (Note 2)	10							pF	Operating and Storage Temperature Range, T_J, T_{STG}	-65 to +175							$^\circ\text{C}$
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NOTES: 1. Measured with $I_F = 5A, I_R = 1A, I_{rr} = 25A$. 2. Measured at 1.0MHz and applied reverse voltage of 4.0VDC.																																																																																																													



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